

## Description

The XE23T712B transient voltage suppressor (TVS) diode is designed for asymmetrical (12V to -7V) protection in multi-point data transmission standard RS-485 applications. The XE23T712B may be used to protect devices from transient voltages resulting from electrostatic discharge (ESD), electrical fast transients (FET), and lightning.

The XE23T712B features 400 Watts ( $t_p=8/20\mu s$ ) of power handling capability to accommodate the higher transient voltage levels which may be expected in extended common mode applications. This provides higher equipment reliability and eliminates the “guess work” required when using zener diodes that are not rated to handle such transient conditions.

The integrated design aids in reducing voltage over-shoot associated with trace inductance. The low clamping voltage of the XE23T712B minimizes the stress on the protected transceiver. The SOT-23 package allows flexibility in the design of “crowded” circuit boards.

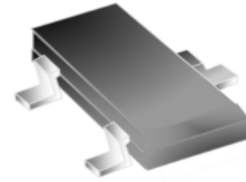
## Features

- ◆ 400 watts peak pulse power ( $t_p=8/20\mu s$ )
- ◆ Protects two +12V to -7V lines
- ◆ Transient protection for asymmetrical data lines to  
IEC61000-4-2 (ESD)  $\pm 15kV$  (air),  
 $\pm 8kV$  (contact)  
IEC61000-4-5 (Lighting) 12A (8/20us)  
IEC61000-4-4(EFT)40A(5/50ns)
- ◆ Low leakage current
- ◆ Low clamping voltage
- ◆ Solid-state silicon-avalanche technology
- ◆ RoHS compliant

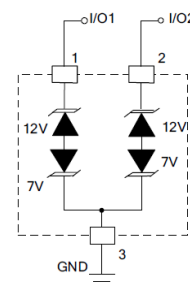
## Applications

- ◆ Protection of RS-485 transceivers with extended common-mode range
- ◆ Networks
- ◆ Security systems
- ◆ Automatic Teller Machines
- ◆ HFC systems

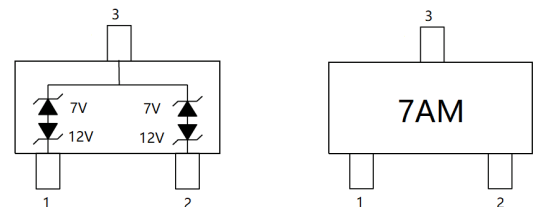
<http://www.xihangsemi.com>



## SOT-23



## Circuit Diagram



## Marking (Top View)

## Order Information

Device	Package	Shipping
XE23T712B	SOT-23	3000/Tape&Reel

## Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{PK}$	400	W
Peak Pulse Current ( $t_p = 8/20\mu s$ )	$I_{pp}$	12	A
ESD according to IEC61000-4-2 air discharge	$V_{ESD}$	$\pm 8$	kV
ESD according to IEC61000-4-2 contact discharge		$\pm 15$	kV
Lead Soldering Temperature	$T_L$	260 (10 sec)	$^{\circ}C$
Operating Temperature	$T_{OP}$	-55 to +125	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55 to +150	$^{\circ}C$

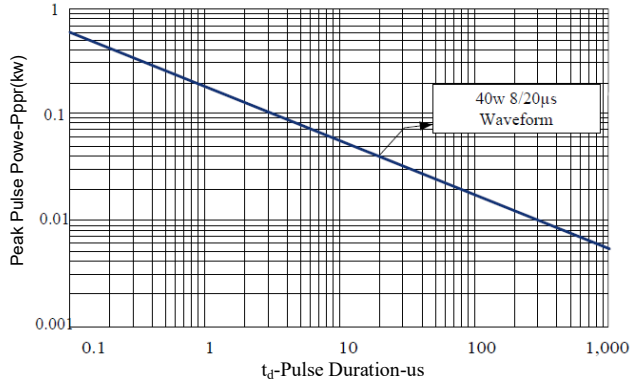
## Electrical Characteristics ( $T_a=25^{\circ}C$ , unless otherwise noted)

Parameter	Symbol	Conditions	Pin1、Pin2 to Pin3 (12V TVS)			Pin3 to Pin1、Pin2 (7V TVS)			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Reverse Stand-off Voltage	$V_{RWM}$				12			7	V
Reverse Leakage Current	$I_R$	$V_R = V_{RWM}$			1.0			1.0	$\mu A$
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1mA$	13.3			7.5			V
Clamping Voltage	$V_C$	$I_{PP}=5A$ $t_p = 8/20\mu s$		20	23		12	15	V
Clamping Voltage	$V_C$	$I_{PP}=12A$ $t_p = 8/20\mu s$		23	26		15	18	V
Junction Capacitance	$C_j$	$V_R=0V$ $f = 1MHz$			75			75	pF
Junction Capacitance	$C_j$	$V_R= V_{RWM}$ $f = 1MHz$		45			45		pF

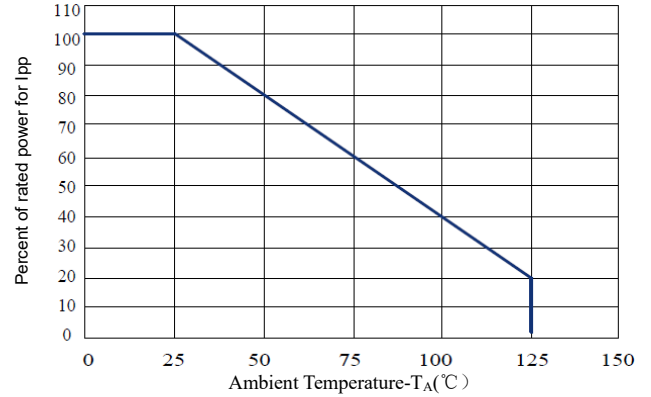
Notes:

- 1) Non-repetitive current pulse, according to IEC61000-4-5.

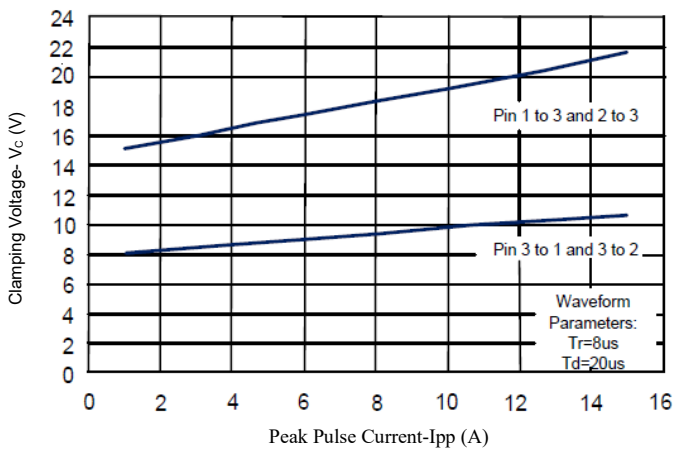
## Typical Characteristics (Ta=25°C, unless otherwise noted)



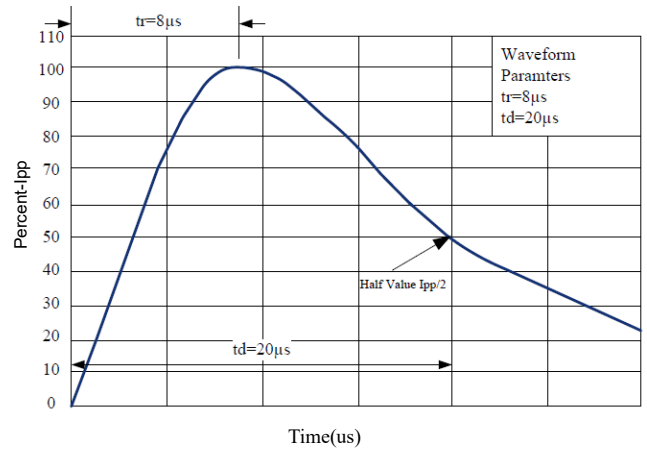
**Peak Pulse Power vs. Pulse Time**



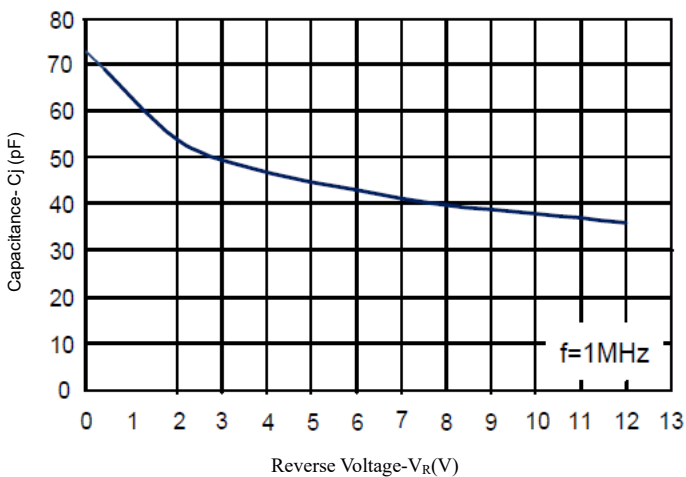
**Power Derating Curve**



**Clamping Voltage vs. Peak Pulse Current**

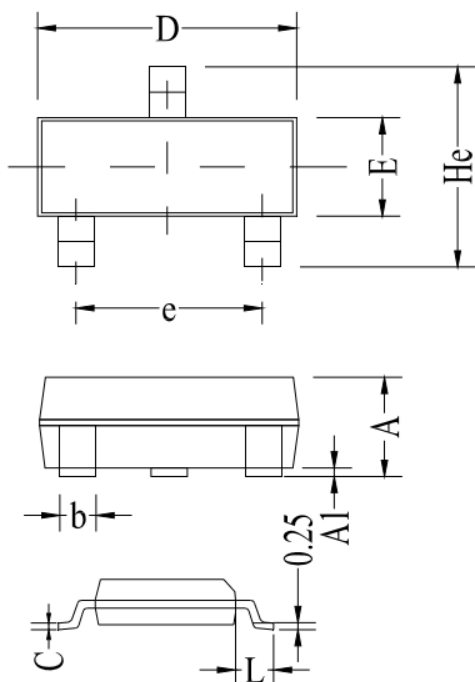


**Pulse Waveform**



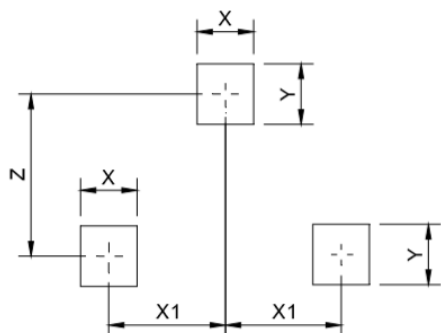
**Capacitance vs. Reverse Voltage**

## Package Outline Dimensions (SOT23-3)



Symbol	Millimeter		Inches	
	Min	Max	Min	Max
A	0.9	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
b	0.25	0.325	0.01	0.013
C	0.22	0.25	0.009	0.01
D	2.8	3.0	0.11	0.118
e	1.8	1.9	0.071	0.075
E	1.2	1.4	0.047	0.055
L	0.30	0.50	0.012	0.02
He	2.25	2.55	0.089	0.1
X	0.8		0.0315	
X1	0.95		0.037	
Y	0.80		0.0315	
Z	2.02		0.0795	

## Recommend Land Pattern (Unit: mm)



Note:

This recommended land pattern is for reference purpose only.

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